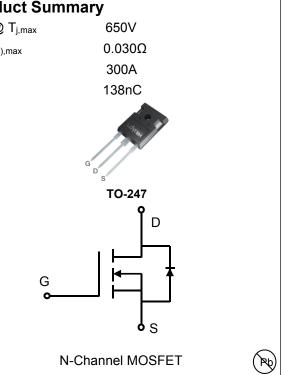


Lonten N-channel 600V, 100A, 0.030Ω LonFET[™] Power MOSFET

Description **Product Summary** LonFET[™] Power MOSFET is fabricated using V_{DS} @ T_{j,max} 650V advanced super junction technology. The resulting 0.030Ω R_{DS(on),max} 300A device has extremely low on resistance, making it IDM especially suitable for applications which require 138nC Q_{g,typ} superior power density and outstanding efficiency. **Features** Ultra low R_{DS(on)} ٠ Ultra low gate charge (typ. $Q_g = 138nC$) **TO-247** ٠ 100% UIS tested ٠ D **RoHS** compliant ٠

Applications

- Power faction correction (PFC). ٠
- Switched mode power supplies (SMPS). ٠
- Uninterruptible power supply (UPS). ٠



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	600	V
Continuous drain current ($T_c = 25^{\circ}C$)	ID	100	A
(T _C = 100°C)		65	A
Pulsed drain current 1)	I _{DM}	300	A
Gate-Source voltage	V _{GSS}	±30	V
Avalanche energy, single pulse ²⁾	E _{AS}	3200	mJ
Power Dissipation TO-247 ($T_c = 25^{\circ}C$)	5	610	W
- Derate above 25°C	PD	4.9	W/°C
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C
Continuous diode forward current	ls	100	A
Diode pulse current	I _{S,pulse}	300	A

Thermal Characteristics TO-247

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R _{θJC}	0.2	°C/W
Thermal Resistance, Junction-to-Ambient	R _{0JA}	49	°C/W
Soldering temperature, wavesoldering only allowed at leads. (1.6mm from case for 10s)	T _{sold}	260	°C



Package Marking and Ordering Information

Device	Device Package	Marking	Units/Tube	Units/Reel
LSB60R030HT	TO-247	LSB60R030HT	30	

Electrical Characteristics T_c = 25°C unless otherwise noted

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Static characteristics				1		
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0 V, I _D =0.25 mA	600	-	-	V
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =0.25 mA	2.5	3.5	4.5	V
Drain cut-off current	I _{DSS}	V _{DS} =600 V, V _{GS} =0 V,				μA
		T _j = 25°C	-	-	1	
		T _j = 125°C	-	10	-	
Gate leakage current, Forward	IGSSF	V _{GS} =30 V, V _{DS} =0 V	-	-	100	nA
Gate leakage current, Reverse	I _{GSSR}	V _{GS} =-30 V, V _{DS} =0 V	-	-	-100	nA
Drain-source on-state resistance	R _{DS(on)}	V _{GS} =10 V, I _D =50 A	-			
		T _j = 25°C	-	0.027	0.030	Ω
		T _j = 150°C	-	0.07	-	
Dynamic characteristics						
Input capacitance	Ciss	V _{DS} = 100 V, V _{GS} = 0 V,	-	9030	-	
Output capacitance	Coss	f = 250 kHz	-	311	-	pF
Reverse transfer capacitance	C _{rss}		-	3.4	-	
Turn-on delay time	t _{d(on)}	V _{DD} = 400 V, I _D = 50 A	-	45	-	
Rise time	tr	R _G = 10 Ω, V _{GS} =15 V	-	107	-	ns
Turn-off delay time	t _{d(off)}		-	304	-	
Fall time	t _f		-	7.8	-	
Gate charge characteristics	L				1	1
Gate to source charge	Q _{gs}	V _{DD} =400 V, I _D =50 A,	-	41.4	-	
Gate to drain charge	Q _{gd}	V _{GS} =0 to 10 V	-	41.0	-	nC
Gate charge total	Qg		-	138	-	
Gate plateau voltage	V _{plateau}	1	-	5.0	-	V
Reverse diode characteristics				,		
Diode forward voltage	V _{SD}	V _{GS} =0 V, I _F =50 A	-	-	1.2	V
Reverse recovery time	trr	V _R =400 V, I _F =30 A,	-	517	-	ns
Reverse recovery charge	Qrr	dl _F /dt=100 A/µs	-	12	-	μC
Peak reverse recovery current	Irrm		-	48	-	А

Notes:

1. Limited by maximum junction temperature, maximum duty cycle is 0.75.

2. I_{AS} = 10A, V_{DD} =60V, Starting T_j= 25°C.

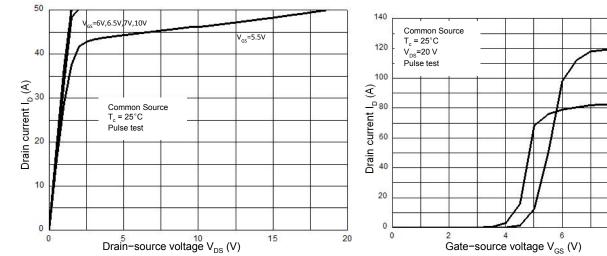
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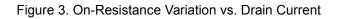
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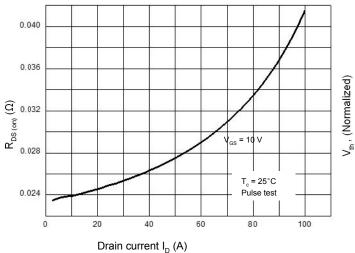


Electrical Characteristics Diagrams

Figure 1. On-Region Characteristics









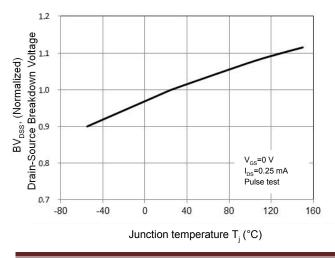


Figure 6. On-Resistance vs. Temperature

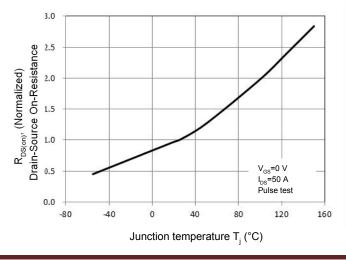


Figure 2. Transfer Characteristics

Figure 4. Threshold Voltage vs. Temperature

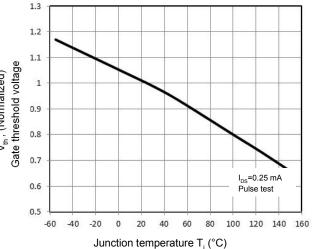
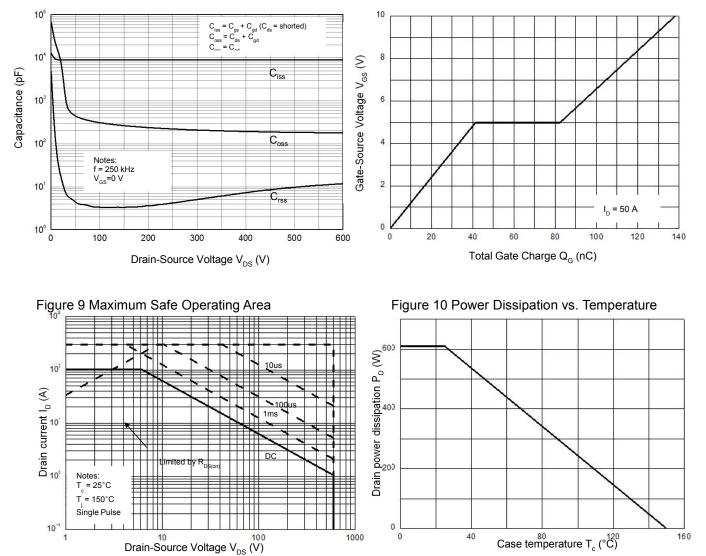




Figure 7. Capacitance Characteristics

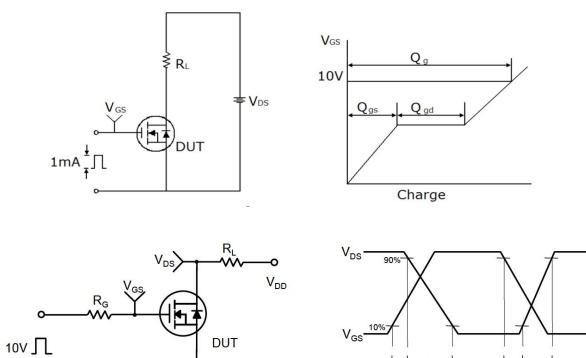
Figure 8. Gate Charge Characterist





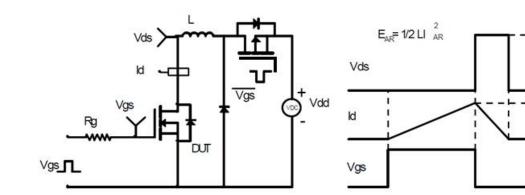
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Gate Charge Test Circuit & Waveform



Unclamped Inductive Switching Test Circuit & Waveforms

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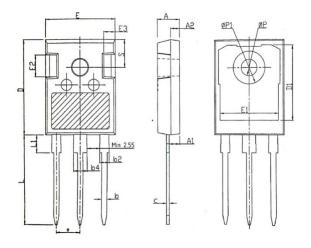


BV_{DSS}

LAR

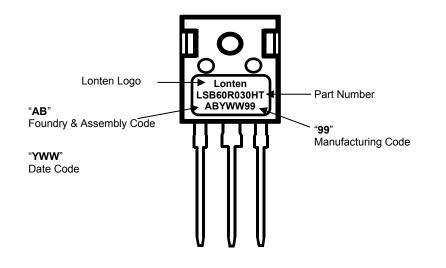


Mechanical Dimensions for TO-247



SYMBOL		mm	
STIVIBOL	MIN	NOM	MAX
А	4.80	5.00	5.20
A1	2.21	2.41	2.59
A2	1.85	2.00	2.15
b	1.11	1.21	1.36
b2	1.91	2.01	2.21
b4	2.91	3.01	3.21
с	0.51	0.61	0.75
D	20.80	21.00	21.30
D1	16.25	16.55	16.85
Е	15.50	15.80	16.10
E1	13.00	13.30	13.60
E2	4.80	5.00	5.20
E3	2.30 2.50		2.70
е	5.44BSC		
L	19.82	19.92	20.22
L1	_	_	4.30
ØP	3.40	3.60	3.80
ØP1	_	_	7.30
S		6.15BSC	

TO-247 Part Marking Information





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